## Switch-mode **Power Rectifiers**

These state-of-the-art devices have the following features:

- Low Power Loss / High Efficiency
- New Package Provides Capability of Inspection and Probe After Board Mounting
- Guardring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- NRVB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free and Halide-Free Devices
- **Mechanical Characteristics:**
- Case: Epoxy, Molded
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting SurfaceTemperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	40	V
Average Rectified Forward Current (Rated $V_R$ , $T_C$ = 165°C)	I <sub>F(AV)</sub>	5	A
Peak Repetitive Forward Current, (Rated V <sub>R</sub> , Square Wave, 20 kHz, T <sub>C</sub> = 165°C)	I <sub>FRM</sub>	10	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	150	A
Storage Temperature Range	T <sub>stg</sub>	-65 to +175	°C
Operating Junction Temperature	TJ	-40 to +175	°C
Unclamped Inductive Switching Energy (10 mH Inductor, Non-repetitive)	E <sub>AS</sub>	40	mJ
ESD Rating (Human Body Model)		3B	
ESD Rating (Machine Model)		M4	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

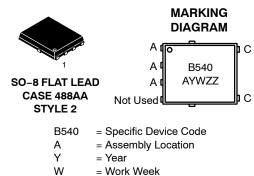


## ON Semiconductor<sup>®</sup>

http://onsemi.com

## SCHOTTKY BARRIER RECTIFIERS **5 AMPERES** 40 VOLTS





= Work Week

77

= Lot Traceability

## **ORDERING INFORMATION**

Device	Package	Shipping†
MBR540MFST1G	SO–8 FL (Pb–Free)	1500 / Tape & Reel
MBR540MFST3G	SO–8 FL (Pb–Free)	5000 / Tape & Reel
NRVB540MFST1G	SO–8 FL (Pb–Free)	1500 / Tape & Reel
NRVB540MFST3G	SO–8 FL (Pb–Free)	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

### THERMAL CHARACTERISTICS

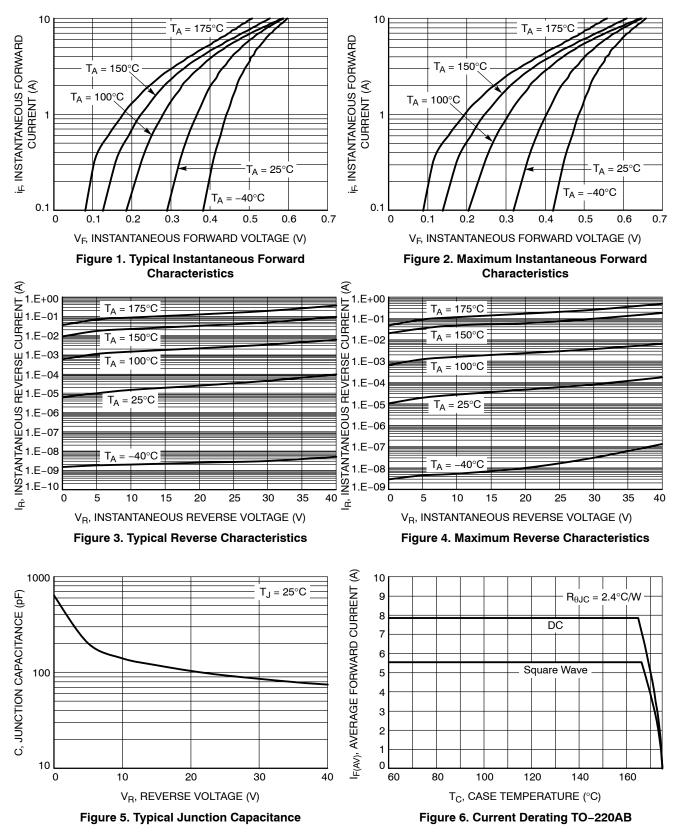
Characteristic	Symbol	Тур	Мах	Unit
Thermal Resistance, Junction-to-Case, Steady State (Assumes 600 mm <sup>2</sup> 1 oz. copper bond pad, on a FR4 board)	R <sub>θJC</sub>	-	4.0	°C/W
	!	<u>.</u>		

#### ELECTRICAL CHARACTERISTICS

Instantaneous Forward Voltage (Note 1) ( $i_F = 5 \text{ Amps}, T_J = 100^{\circ}\text{C}$ ) ( $i_F = 5 \text{ Amps}, T_J = 25^{\circ}\text{C}$ )	٧F	0.44 0.50	0.54 0.58	V
Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_J = 100^{\circ}$ C) (Rated dc Voltage, $T_J = 25^{\circ}$ C)	i <sub>R</sub>	6 0.100	20 2	mA

1. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

## **TYPICAL CHARACTERISTICS**



## **TYPICAL CHARACTERISTICS**

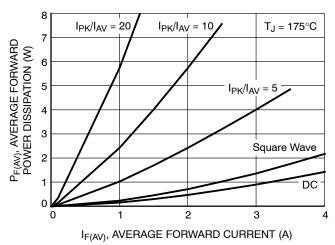


Figure 7. Forward Power Dissipation

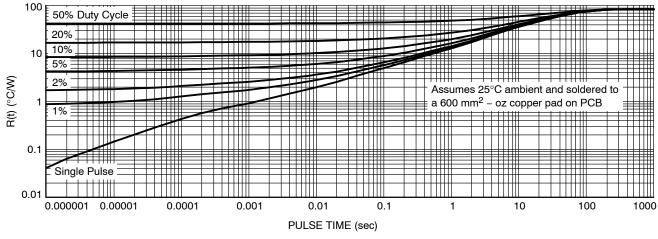


Figure 8. Thermal Characteristics





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